

Vishay Siliconix

N-Channel 30 V (D-S) MOSFET



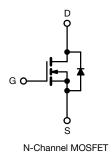
Marking code: L6

PRODUCT SUMMARY					
V _{DS} (V)	30				
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 10 \text{ V}$	0.047				
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 4.5 \text{ V}$	0.065				
Q _g typ. (nC)	3.0				
I _D (A)	4.0				
Configuration	Single				

FEATURES

- TrenchFET® power MOSFET
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ORDERING INFORMATION			
Package	SOT-23 (TO-236)		
Lead (Pb)-free	Si2306BDS-T1-E3		
Lead (Pb)-free and halogen-free	Si2306BDS-T1-GE3		

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	30	V
Gate-source voltage		V _{GS}	± 20	
	T _A = 25 °C		4.0 ^c	
Continuous dusin surrent /T 150 °C) 3 h	T _A = 70 °C		3.5 ^c	
Continuous drain current ($T_J = 150 ^{\circ}\text{C}$) ^{a, b}	T _A = 25 °C	I _D	3.16 ^d	
	T _A = 70 °C		2.7 ^d	А
Pulsed drain current		I _{DM}	20	
Continuous source-drain diode current a, b			1.04 ^c	
		I _S	0.62 d	
	T _A = 25 °C		1.25 ^c	
Maximum power dissipation ^{a, b}	T _A = 70 °C	_	0.8 ^c	14/
	T _A = 25 °C	P _D	0.75 d	W
	T _A = 70 °C		0.48 d	
Operating junction and storage temperature ran	ge	T _J , T _{sta}	-55 to +150	°C

Notes

- a. Surface mounted on 1" x 1" FR4 board, $t \le 5 \text{ s}$
- b. Pulse width limited by maximum junction temperature
- c. t = 5 s
- d. Steady state



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THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^a	t ≤ 5 s	В	60	100	
Maximum junction-to-ambient ~	Steady state	R_{thJA}	130	166	°C/W
Maximum junction-to-foot (drain)	Steady state	R _{thJF}	60	75	

Note

a. Surface mounted on 1" x 1" FR4 board

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static			-				
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0	-	3.0	V	
Gate-body leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
Zava gata valtaga duain avuvant		V _{DS} = 30 V, V _{GS} = 0 V	-	-	0.5		
Zero gate voltage drain current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C	-	-	10	μA	
On-state drain current a	I _{D(on)}	$V_{DS} \ge 4.5 \text{ V}, V_{GS} = 10 \text{ V}$	6	-	=.	Α	
Drain agures en etata registance 3	В	V _{GS} = 10 V, I _D = 3.5 A		0.038	0.047	Ω	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 2.8 A	-	0.052	0.065	32	
Forward transconductance a	9 _{fs}	$V_{DS} = 4.5 \text{ V}, I_{D} = 2.5 \text{ A}$	-	7.0	=	S	
Diode forward voltage	V _{SD}	V _{GS} = 0 V, I _S = 1.25 A	-	0.8	1.2	V	
Dynamic							
Gate charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 2.5 \text{ A}$	-	3.0	4.5		
Total gate charge	Q _{gt}		-	6	9	nC	
Gate-source charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$	-	1.6	-	110	
Gate-drain charge	Q_{gd}		-	0.6	-		
Gate resistance	R_g	f = 1 MHz	2.0	5.0	7.5	Ω	
Input capacitance	C _{iss}		-	305	=		
Output capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	65	=	pF	
Reverse transfer capacitance	C _{rss}		-	29	=.		
Switching							
Turn-on delay time	t _{d(on)}		-	7	11		
Rise time	t _r	$V_{DD} = 15 \text{ V}, R_L = 15 \Omega, I_D \cong 1 \text{ A},$	-	12	18		
Turn-off delay time	t _{d(off)}	$V_{GEN} = 0 \text{ V}, R_g = 6 \Omega$	-	14	25	ns	
Fall time	t _f		-	6	10		
Reverse recovery time	t _{rr}	1 4 05 4 4:/44 400 4/ -	-	14	21		
Body diode reverse recovery charge	Q _{rr}	$I_F = 1.25 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	-	6	10	nC	

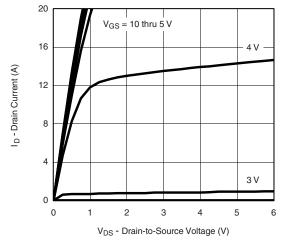
Notes

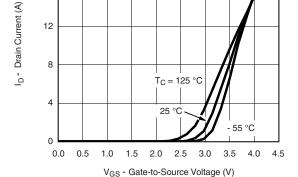
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





20

16

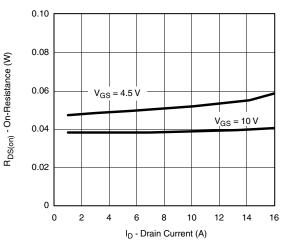
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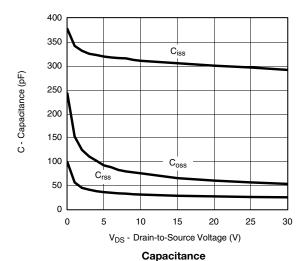
0.8

- 50

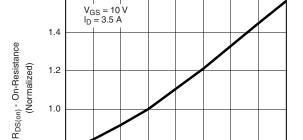
Output Characteristics

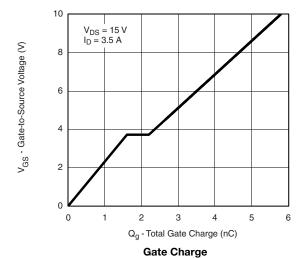


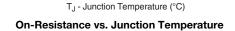




On-Resistance vs. Drain Current







50

75

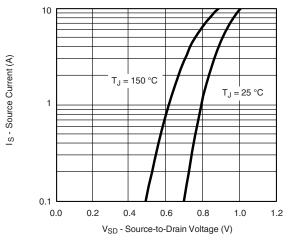
100

25

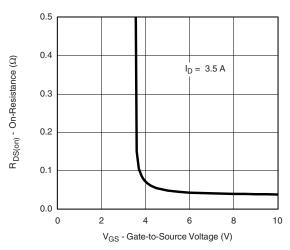
125 150



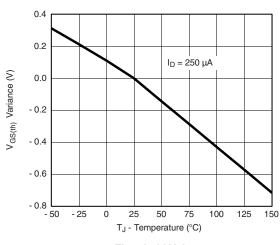
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



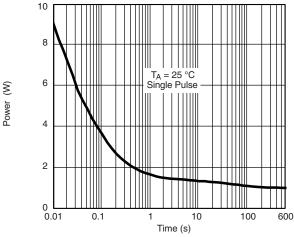
Source-Drain Diode Forward Voltage



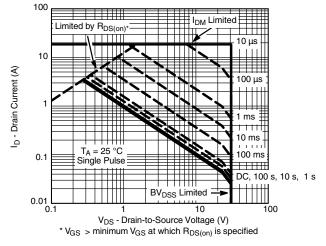
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



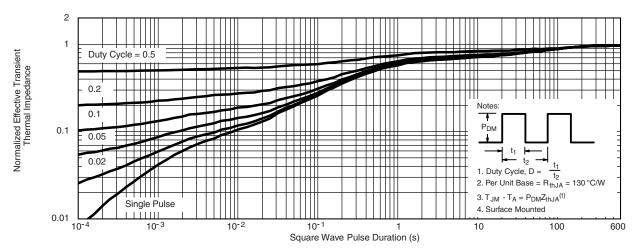
Single Pulse Power



Safe Operating Area



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

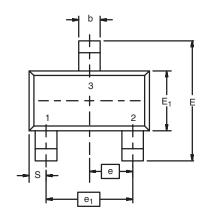


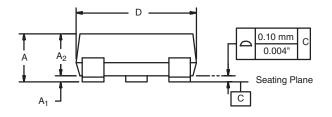
Normalized Thermal Transient Impedance, Junction-to-Ambient

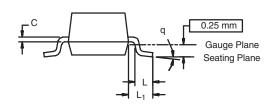
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SOT-23 (TO-236): 3-LEAD







Dim	MILLIN	IETERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.074	8 Ref	
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025	i Ref	
S	0.50 Ref		Ref 0.020 Ref		
q	3°	8°	3°	8°	

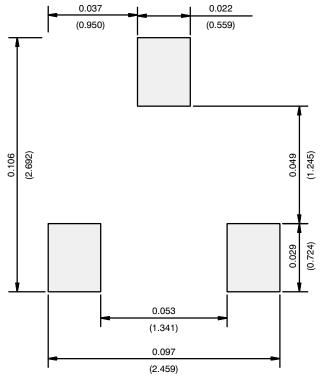
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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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